

## InGaAs PIN PHOTODIODES

## PD-1110 SERIES

### FEATURES

- 2 High responsivity for dual windows at 1310 nm and 1550 nm
- 2 Low dark current
- 2 Quick pulse response
- 2 Hermetically sealed 3-pin metal case
- 2 Active diameter 300  $\mu\text{m}$

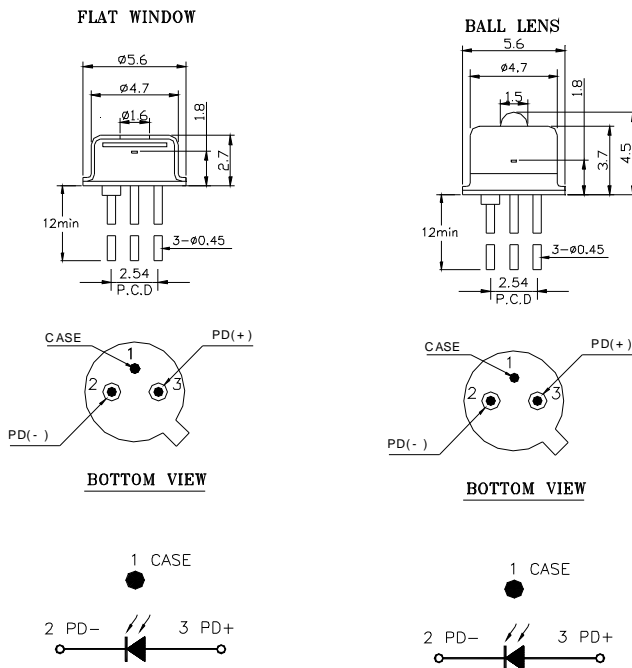
### DESCRIPTION

PD-1110 series InGaAs Photodiode are suited to receive the light at the wavelength range from 1100 nm to 1620 nm. With high reliability, PD-1110 series are the best choice for telecom and datacom application.

ELECTRICAL AND OPTICAL CHARACTERISTICS ( $T_C=25^\circ\text{C}$ )						
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
	Active Area			300		$\mu\text{m}$
	Detection Range		1100		1620	nm
R	Responsivity	$V_R=5\text{V}, \lambda=1300\text{nm}$	0.85		-	A/W
		$V_R=5\text{V}, \lambda=1550\text{nm}$	0.90	-		
$I_{\text{dark}}$	Dark Current	$V_R=5\text{V}$		2	5	nA
C	Capacitance	$V_R=5\text{V}$		6	10	pF
$T_r/T_f$	Rise/Fall Time	$V_R=5\text{V}, 10\sim 90\%$			2	ns
BW	Bandwidth	$V_R=5\text{V}$	500			MHz

ABSOLUTE MAXIMUM RATINGS ( $T_C=25^\circ\text{C}$ )			
Symbol	Parameter	Ratings	Unit
$P_o$	Input Optical Power	10	mW
$V_{RD}$	Reverse Voltage	20	V
$I_{FD}$	Forward Current	10	mA
$T_{opr}$	Operating Temperature	-40~+85	$^\circ\text{C}$
$T_{stg}$	Storage Temperature	-40~+85	$^\circ\text{C}$

MECHANICAL DIMENSION (mm) and PIN ASSIGNMENT



**Note:** 1. Specifications subject to change without notice.  
 2. Other PIN assignment is available upon request.

ORDER INFORMATION

Part No.: P D - 1 1 1 □

Code	Package
0	Ball Lens Cap
5	Flat Window Cap